

NM10 *MOTOR PROTECTION RELAY* THE BASIC SOLUTION FOR SMALL / MEDIUM SIZE MOTOR PROTECTION

— Application

The relay type NM10 can be used for protection of small/medium size motors in LV and MV systems powered through lines of:

- · Any length in solidly or low resistance grounded systems
- Small length in ungrounded or Petersen coil and/or high resistance grounded systems.



- Protective & control functions

- 26 Thermal protection with RTD probes (optional)
- 37 Undercurrent
- 46 Negative-sequence overcurrent
- 49 Thermal image
- 50/51 Phase overcurrent
- 50S/51LR/14Locked rotor
- 50N/51N Residual overcurrent
- 66 Maximum number of startings (Restart inhibition)
- BF Circuit breaker failure
- 74CT CT supervision
- 74TCS Trip circuit supervision

Measuring inputs

Three phase current inputs and one residual current input, with nominal currents independently selectable at 1 A or 5 A through DIP-switches.

— Firmware updating

The use of flash memory units allows on-site firmware updating.

— Two set point profiles (A,B)

Two independent groups of settings are provided. Switching from profiles may be operated by means of MMI, binary input and communication.

— Construction

According to the hardware configurations, the NM10 protection relay can be shipped in various case styles depending on the required mounting options (flush, projecting mounting, rack or with separate operator panel).

— Binary inputs

Two binary inputs are available with programmable active state (active-ON/active-OFF) and programmable timer (active to OFF/ ON or ON/OFF transitions).

Several presettable functions can be associated to each input.

— Modular design

In order to extend I/O capability, the NM10 hardware can be customized through external auxiliary modules:

- MRI Output relays and LEDs.
- MID16 Binary inputs.
- MCI 4...20 mA converters.
- MPT Pt100 thermal probes.



Blocking input/outputs

One output blocking circuit and one input blocking circuit are provided.

The output blocking circuits of one or several Pro_N relays, shunted together, must be connected to the input blocking circuit of the protection relay, which is installed upstream in the electric plant. The output circuit works as a simple contact, whose condition is detected by the input circuit of the upstream protection relay.

Use of suitable pilot wire to fiber optic converters (BFO) allows to perform fast and reliable accelerated logic selectivity on radial and closed ring networks.

— Output relays

Six output relays are available (two changeover, three make and one break contacts); each relay may be individually programmed as normal state (normally energized, de-energized or pulse) and reset mode (manual or automatic).

A programmable timer is provided for each relay (minimum pulse width). The user may program the function of each relay according to a matrix (tripping matrix) structure.

MMI (Man Machine Interface)

The user interface comprises a membrane keyboard, a backlight LCD alphanumeric display and eight LEDs.

The green ON LED indicates auxiliary power supply and self diagnostics, two LEDs are dedicated to the Start and Trip (yellow for Start, red for Trip) and five red LEDs are user assignable.



— Communication

Multiple communication interfaces are implemented:

- One RS232 local communication front-end interface for communication with ThySetter setup software
 Two back-end interfaces for communication with remote mon-
- iwo back-end interfaces for communication with remote monitoring and control systems by:
 RS485 port using MedBuc@ RTIL IEC 60070 5 102 cr DNP2
- RS485 port using ModBus® RTU, IEC 60870-5-103 or DNP3 protocol.

- Ethernet port (RJ45 or optical fiber) using ModBus/TCP protocol.

Programming and settings

All relay programming and adjustment operations may be performed through MMI (Keyboard and display) or using a Personal Computer with the aid of the ThySetter software.

The same PC setup software is required to set, monitor and configure all \mbox{Pro}_N devices.

Full access to the available data is provided:

- Read status and measures.
- Read/edit settings (on-line or off-line edit).
- Two session level (User or Administrator) with password for sensible data access are provided.

ThySetter					
ThySetter - V3.6.1				l	
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	00040000	914 (0		
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 Blocco seletivo - BLOCK2 	LEDs intervento I*	PIRL	L6		File
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— Control and monitoring

- Several predefined functions are implemented:
- Activation of two set point profiles
- Phase CTs monitoring (74CT)
- Logic selectivity
- Cold load pickup (CLP) with block or setting change
- Trip circuit supervision (74TCS)
- Remote tripping
- Synchronization
- Circuit Breaker commands and diagnostic

User defined logic may be customized according to IEC 61131-3 standard protocol (PLC).

Circuit Breaker

Several diagnostic, monitoring and control functions are provided:

- Health thresholds can be set; when the accumulated duty (ΣI or $\Sigma I^2 t$), the number of operations or the opening time exceeds the threshold an alarm is activated
- Breaker failure (BF); breaker status is monitored by means 52a-52b and/or through line current measurements
- Trip circuit supervision (74TCS)
- Breaker control; opening and closing commands can be carried out locally or remotely

Cold Load Pickup (CLP)

Cold load pickup element prevents unwanted tripping in case of temporary overcurrents produced at the motor starting.

- Three different operating modes are provided:
- OFF the function is disabled
- Each protective element can be blocked for a programmable time
- Each threshold can be increased for a programmable time.

Logic selectivity

With the aim of providing a fast selective protection system some protective functions may be blocked (pilot wire accelerated logic). To guarantee maximum fail-safety, the relay performs a run time monitoring for pilot wire continuity and pilot wire shorting. Exactly the output blocking circuit periodically produces a pulse, having a small enough width in order to be ignored as an effective blocking signal by the input blocking circuit of the upstream protection, but suitable to prove the continuity of the pilot wire.

Self diagnostics

All hardware and software functions are repeatedly checked and any anomalies reported via display messages, communication interfaces, LEDs and output relays.

Anomalies may refer to:

 Hw faults (auxiliary power supply, output relay coil interruptions, MMI board...)

- Sw faults (boot and run time tests for data base, EEPROM memory checksum failure, data BUS,...)
- Pilot wire faults (break or short in the wire)
- Circuit breaker faults.

— Metering

NM10 provides metering values for phase and residual currents, making them available for reading on a display or to communication interfaces.

Input signals are sampled 24 times per period and the RMS value of the fundamental component is measured using the DFT (Discrete Fourier Transform) algorithm and digital filtering.

With DFT the RMS value of 2nd, 3rd, 4th and 5th harmonic of phase current are also measured.

On the base of the direct measurements, the minimum-peakfixed-rolling demand, mean-minimum-maximum absolute phase currents are processed.

The measured signals can be displayed with reference to nominal values or directly expressed in amperes.

— Event storage

Several useful data are stored for diagnostic purpose; the events are stored into a non volatile memory.

They are graded from the newest to the older after the "Events reading" command (ThySetter) is issued:

• Sequence of Event Recorder (SER)

The event recorder runs continuously capturing in circular mode the last three hundred events upon trigger of binary in-put/output.

- Sequence of Fault Recorder (SFR) The event recorder runs continuously capturing in circular mode the last twenty events upon trigger of binary input/output and/or element pickup (start-trip)
- Trip counters.

– Digital Fault Recorder (DFR)

Upon trigger of tripping/starting of each function or external signals, the relay records in COMTRADE format:

- Oscillography with instantaneous values for transient analysis
- RMS values of the measured signals for long time periods analysis
- Logic states (binary inputs and output relays).
- Note A license for Digital Fault Recorder function is required, for purchase procedure please contact Thytronic. The records are stored in nonvolatile memory



THYTRONIC -

S P E C I F I C A T I O N S

GENERAL

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GENERAL		INPUT
 Mechanical data Mounting: flush, projecting, rac Mass (flush mounting case) 	k or separated operator panel 2.0 kg	— Auxiliary Nominal v Operative r
 Insulation tests Reference standards High voltage test 50Hz Impulse voltage withstand (1.2/50 points) Insulation resistance 	EN 60255-5 2 kV 60 s μs) 5 kV >100 MΩ	Power cor • Maximu • Maximu — Phase cu
 Voltage dip and interruption Reference standards 29 	EN 61000-4-	Nominal c Permanen Thermal o Rated con
— EMC tests for interference important of the second se	EN 60255-22-1 1 kV-2.5 kV EN 60255-22-2 8 kV EN 60255-22-4 4 kV EN 60255-22-6 10 V EN 60255-4-3 10 V/m EN 61000-4-5 2 kV EN 61000-4-8 1 kA/m EN 61000-4-12 2.5 kV EN 61000-4-12 2 kV	 Residual Nominal c Permanen Thermal or Rated con Binary in Quantity Type Max perm Max construction
 Emission Reference standards Conducted emission 0.1530 MHz Radiated emission 301000 MHz 	EN 61000-6-4 (ex EN 50081-2) Class A Class A	— Block inp Quantity Type pol Max consi
 Climatic tests Reference standards ENEL R CLI 01, CEI 50 	IEC 60068-x,	<u>OUTPU</u> — Output re <i>Quantity</i>
 Mechanical tests Reference standards 1, 21-2, 21-3 	EN 60255-21-	 Type of a Type of a Type of a Type of a Nominal c
 Safety requirements Reference standards Pollution degree Reference voltage Overvoltage Pulse voltage Reference standards Protection degree: Front side Rear side, connection terminals 	EN 61010-1 3 250 V III 5 kV EN 60529 IP52 IP20	Nominal v Breaking d • Direct cu • Alternati Make Short dura — Block out Quantity Type
— Environmental conditions Ambient temperature Storage temperature Relative humidity Atmospheric pressure	-25+70 °C -40+85 °C 1095 % 70110 kPa	 LEDs Quantity ON/fail (Start (ye Trip (red Allocata
 Certifications Product standard for measuring re CE conformity 	elays EN 50263	GENER
EMC Directive Low Voltage Directive Type tests COMMUNICATION INTER	89/336/EEC 2006/95/EC IEC 60255-6	— Rated val Relay phas Phase CTs Relay resid Residual C Relay nom
Local PC RS232 <i>Network:</i> • RS485 • Ethernet 100BaseT Protocol ModBus® RTU/	19200 bps 120057600 bps 100 Mbps /IEC 60870-5-103/DNP3-TCP/IP	Binary in ON delay t OFF delay Logic

INPUT CIRCUITS

_	Auxiliary power supply Uaux Nominal value (range) 2448 Vac/dc, 115 Operative range (each one of the above nom	
	 Power consumption: Maximum (energized relays, Ethernet 1 Maximum (energized relays, Ethernet F 	TX) 10 W (20 VA)
	Phase current inputsNominal current In1 A or 5 A selePermanent overloadThermal overload (1s)Rated consumption (for any phase)	ctable by DIP Switches 25 A 500 A $\leq 0.002 \text{ VA} (I_n = 1 \text{ A})$ $\leq 0.04 \text{ VA} (I_n = 5 \text{ A})$
	Residual current input Nominal current I_{En} 1 A or 5 A setPermanent overload1Thermal overload (1s)3Rated consumption ≤ 0.006 VA ($I_{En} = 1$ A	electable by DIP Switch 25 A 500 A
—	Binary inputs Quantity	2
	Type Max permissible voltage 1 Max consumption, energized	dry inputs 19265 Vac/19300 Vdc 3 mA
_	Block input (Logic selectivity) Quantity Type polarized wet input (powered by i Max consumption, energized	1 nternal isolated supply) 5 mA
	OUTPUT CIRCUITS	
_	 Type of contacts K3, K4, K5 Type of contacts K6 Nominal current Nominal voltage/max switching voltage 	6 ngeover (SPDT, type C) nake (SPST-NO, type A) oreak (SPST-NC, type B) 8 A 250 Vac/400 Vac
	 Breaking capacity: Direct current (L/R = 40 ms) Alternating current (λ = 0,4) Make Short duration current (0,5 s) 	50 W 1250 VA 1000 W/VA 30 A
_	Block output (Logic selectivity) Quantity Type	1 optocoupler
	LEDs Quantity • ON/fail (green) • Start (yellow) • Trip (red) • Allocatable (red)	8 1 1 1 5
	GENERAL SETTINGS	
_	Rated values Relay phase nominal current <i>I</i> _n Phase CTs nominal primary current <i>I</i> _{np} Relay residual nominal current <i>I</i> _{En} Residual CT nominal primary current <i>I</i> _{Enp} Relay nominal frequency <i>f</i> _n	1 A, 5 A 1 A10 kA 1 A, 5 A 1 A10 kA 50, 60 Hz
_	Binary input timers ON delay time (IN1 <i>t</i> _{ON} , INx <i>t</i> _{ON}) OFF delay time (IN1 <i>t</i> _{OFF} , INx <i>t</i> _{OFF}) Logic	0.00100.0 s 0.00100.0 s Active-ON/Active-OFF

— Relay output timers Minimum pulse width t _{TB}	0.0000.500 s	
PROTECTIVE FUNCTIONS		
Base current - IB Base current (/B)	0.201.50 <i>I</i> n	
lote - Assuming that the secondary rated current of the	line CT's equals the	
rated current of the relay, as usually happens, the between the rated current of the protected motor a current of the CT's.		
 Thermal protection with RTD thermomet Alarm 	ric probes - 26	
 Alarm threshold θ_{ALx} (x=18) Operating time t_{θALx} (x=18) 	0200 °C 0100 s	
<i>Trip</i> • Trip threshold θ> _x (x=18)	0200 °C	
• Operating time $t_{\Theta > x}$ (x=18)	0100 s	
lote: The element becomes available when the MPT mo connected to Thybus	dule is enabled and	
– Undercurrent - 37 I< Element		
 I< Inhibition time (t_{inh}<) 	0.00200 s	
Definite time 37 First threshold definite time (I<def)< li=""> </def)<>	0.301.00 /в	
 <i>I</i><def (<i="" operating="" time="">t<def)< li=""> </def)<></def>	0.10600 s	
 Negative sequence overcurrent - 46 l₂> Element 	-	_
 <i>I</i>₂> Curve type (<i>I</i>₂>Curve) 	DEFINITE	
IEC/BS A, B, C, ANSI/IEEE • I _{2CLP} > Activation time (t _{2CLP} >)	: MI, VI, EI, EM, I4 0.00200 s	
 <i>I</i>₂> Reset time delay (<i>t</i>₂>_{RES}) <i>Definite time</i> 	0.00100.0 s	
 46 First threshold definite time (<i>I</i>₂>_{def}) <i>I</i>₂>_{def} within CLP (<i>I</i>_{2CLP>def}) 	0.101.00 / _B 0.105.00 / _B	
 <i>I</i>_{2>def} Operating time (<i>t</i>_{2>def}) <i>Inverse time</i> 	0.03200 s _	_
 46 First threshold inverse time (I_{2>inv}) I_{2>inv} within CLP (I_{2CLP>inv}) 	0.101.00 / _B 0.105.00 / _B	
• $I_{2>inv}$ Operating time ($t_{2>inv}$) $I_{2>>> Element$	0.0260.0 s	
 <i>I</i>_{2CLP}>> Activation time (<i>t</i>_{2CLP>>}) 	0.00200 s	
 <i>I</i>₂>> Reset time delay (<i>t</i>₂>>_{RES}) Definite time 	0.00100.0 s	
 46 Second threshold definite time (I_{2>>def}) 	0.101.00 / _B	
 <i>I</i>_{2>>def} within CLP (<i>I</i>_{2CLP>>def}) <i>I</i>_{2>>def} Operating time (<i>t</i>_{2>>def}) 	0.105.00 / _B 0.03200 s	
	0.00200 3	
 Thermal image - 49 Common configuration: 		
• Initial thermal image $\Delta \Theta_{IN} (Dth_{IN})$	0.01.0 <i>Δ</i> θ _B	
 Overload coefficient on starting (K_{ST}) Negative sequence current heating coefficient 	1.03.0 ent (<i>K</i> ₂) 010	
• Heating time constant τ + (<i>T</i> +)	1200 min	
 Cooling time constant τ– (T-) 	1.06.0 τ+	
 Dth_{CLP} Operating mode (Dth_{CLP Mode}) Blockin Dth_{CLP} Activation time (t_{DthCLP}) Dth 411 Element 	ng/Change setting 0.00200 s	
 DthAL1 Element 49 First alarm threshold Δθ_{AL1} (Dth_{AL1}) DthAL2 Element 	0.31.0 Δθ _B	
• 49 Second alarm threshold $\Delta \theta_{AL2} (Dth_{AL2})$ Dth> Element	0.51.2 <i>Δ</i> θ _B	
• 49 Trip threshold $\Delta \theta$ (<i>Dth</i> >)	1.2 <i>Δ</i> θ _B	
– Phase overcurrent - 50/51 I> Element	-	_
 I> Curve type (I>Curve) IEC/BS A, B, C, AN 	DEFINITE	
	RECTIFIER, EM, I ² t	
 I_{CLP} > Activation time (t_{CLP}) I> Reset time delay (t>_{RES}) 	0.00200 s 0.00100.0 s	

Nefinite time

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Definite time	
 50/51 First threshold definite time (I>def) 	0.10040.0 <i>I</i> n
• <i>I</i> > _{def} within CLP (<i>I</i> _{CLP>def})	0.10040.0 /n
 <i>I</i>>def Operating time (<i>t</i>>def) 	0.04200 s
	0.04200 3
Inverse time	0 100 20 00 /
 50/51 First threshold inverse time (<i>I</i>>_{inv}) <i>I</i>>_{inv} within CLP (<i>I</i>_{CLP>inv}) 	0.10020.00 /n
• <i>I></i> inv Operating time (<i>t</i> >inv)	0.10020.00 / _n 0.0260.0 s
	0.0200.0 3
l>> Element	
 I>> Curve type (I>>Curve) 	DEFINITE, I ² t
 I_{CLP}>> Activation time (t_{CLP>>}) 	0.00200 s
 I>> Reset time delay (t>>_{RES}) 	0.00100.0 s
Definite time	
 50/51 Second threshold definite time (I>>def) 	0.10040.0 <i>I</i> n
 I>>def within CLP (I_{CLP>>def}) 	0.10040.0 <i>I</i> _n
 I>>_{def} Operating time (t>>_{def}) 	0.0310.00 s
Inverse time	
Inverse time	0 100 20 00 /
 50/51 Second threshold inverse time (<i>I</i>>>inv) <i>I</i>>>inv within CLP (<i>I</i>_{CLP>>inv}) 	0.10020.00 / _n 0.10020.00 / _n
• $I >>_{inv}$ Operating time $(t >>_{inv})$	0.0210.00 s
	0.0210.00 3
l>>> Element	
 I_{CLP}>>> Activation time (t_{CLP>>>}) 	0.00200 s
 I>>> Reset time delay (t>>>_{RES}) 	0.00100.0 s
Definite time	
 50/51 Third threshold definite time (/>>>def) 	0.10040.0 <i>I</i> n
 />>>def within CLP (I_{CLP>>>def}) 	0.10040.0 <i>I</i> n
 I>>>_{def} Operating time (t>>>_{def}) 	0.0310.00 s
- Locked rotor - 50S/51LR/14	
I _{LR} > Element	
 <i>I</i>_{LRCLP}> Operating mode (<i>Mode 51LR</i>) With/wit 	
 <i>I</i>_{LRCLP}> Activation time (<i>t</i>_{LRCLP}>) 	0.00200 s
Definite time	
 51LR First threshold definite time (I_{LR>def}) 	0.908.00 / _B
 51LR First threshold definite time (<i>I</i>_{LR>def}) <i>I</i>_{LR>def} Operating time (<i>t</i>_{LR>def}) 	0.908.00 / _B 0.10200 s
• $I_{LR>def}$ Operating time $(t_{LR>def})$	
 <i>I</i>_{LR>def} Operating time (<i>t</i>_{LR>def}) Residual overcurrent - 50N/51N 	
 <i>I</i>_{LR>def} Operating time (<i>t</i>_{LR>def}) Residual overcurrent - 50N/51N <i>I</i>_{E>} Element 	0.10200 s
 <i>I</i>_{LR>def} Operating time (<i>t</i>_{LR>def}) Residual overcurrent - 50N/51N <i>I</i>_{E>} <i>Element</i> <i>I</i>_{E>} Curve type (<i>I</i>_{E>}Curve) 	0.10200 s DEFINITE
 /_{LR>def} Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE 	0.10200 s DEFINITE EE MI, VI, EI, EM
 /_{LR>def} Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_{ECLP>}</i> Activation time (t_{ECLP>}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s
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 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I</i>_E> <i>Element</i> <i>I</i>_E> Curve type (<i>I</i>_E>Curve)	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i> Activation time (t_{ECLP>}) <i>I_E</i> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E>_{def}</i>) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 <i>I</i> En
 /_{LR>def} Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i>CLP> Activation time (t_{ECLP>}) <i>I_E</i>> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E>_{def}</i>) <i>I_E>_{def}</i> within CLP (<i>I_{ECLP>def}</i>) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i> Activation time (t_{ECLP>}) <i>I_E</i> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E>_{def}</i>) <i>I_E>_{def}</i> within CLP (<i>I_{ECLP>def}</i>) <i>I_{E>def}</i> Operating time (t_E>_{def}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 <i>I</i> En
 /_{LR>def} Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) <i>IEC/BS A, B, C, ANSI/IE</i> <i>I_E</i> Activation time (t_{ECLP>}) <i>I_E</i> Reset time delay (t_E>_{RES}) <i>Definite time</i> 50N/51N First threshold definite time (<i>I_E>_{def}</i>) <i>I_E>_{def}</i> within CLP (<i>I_{ECLP>def}</i>) <i>I_{E>def}</i> Operating time (t_{E>def}) <i>I_{E>def}</i> Operating time (t_{E>def}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.00210.00 s
 /_{LR>def} Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i>CLP> Activation time (t_{ECLP>}) <i>I_E</i> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E></i>_{def}) <i>I_E></i>_{def} within CLP (<i>I_{ECLP>def}</i>) <i>I_E></i>_{def} Operating time (t_E>_{def}) <i>Inverse time</i> 50N/51N First threshold inverse time (<i>I_E></i>_{inv}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.0022.00 /En
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i>CLP> Activation time (t_{ECLP>}) <i>I_E</i> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E></i>_{def}) <i>I_E></i>_{def} within CLP (<i>I_{ECLP>def}</i>) <i>I_E></i>_{def} Operating time (t_E>_{def}) <i>I_{Nverse time}</i> 50N/51N First threshold inverse time (<i>I_E></i>_{inv}) <i>I_E></i>_{inv} within CLP (<i>I_{ECLP>inv}</i>) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.0022.00 /En 0.0022.00 /En
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N <i>I_E> Element</i> <i>I_E></i> Curve type (<i>I_E></i>Curve) IEC/BS A, B, C, ANSI/IE <i>I_E</i>CLP> Activation time (t_{ECLP>}) <i>I_E</i>> Reset time delay (t_E>_{RES}) Definite time 50N/51N First threshold definite time (<i>I_E></i>_{def}) <i>I_E</i>> def Operating time (t_E>_{def}) <i>I_E></i> def Operating time (t_E>_{def}) <i>I_E></i> inv within CLP (<i>I_{ECLP>def}</i>) <i>I_E></i> def Operating time (t_E>_{def}) <i>I_E></i> inv within CLP (<i>I_{ECLP>inv}</i>) <i>I_E></i> inv Operating time (t_E>_{inv}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.0022.00 /En
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N /E> Element /E> Curve type (/E>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (t_{ECLP>}) /E> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (/E>def) /E>def Operating time (t_E>def) /E>def Operating time (t_E>def) /E>def Operating time (t_E) /E>inv within CLP (/ECLP>inv) /E>inv Operating time (t_E) /E>inv Operating time (t_E) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.002200 /En 0.002200 /En 0.00260.0 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N /E> Element /E> Curve type (/E>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (t_{ECLP>}) /E> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (/E>def) /E>def Operating time (t_E>def) /INVERSE time 50N/51N First threshold inverse time (I_E>inv) /E>inv within CLP (I_{ECLP>inv}) /E>inv within CLP (I_{ECLP>inv}) /E>inv Operating time (t_E>inv) /E>inv Operating time (t_E>inv) /E>inv Operating time (t_E>inv) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.002200 /En 0.002200 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N IE> Element IE> Curve type (I_E>Curve) IEC/BS A, B, C, ANSI/IE IECLP> Activation time (t_{ECLP>}) I_E> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (I_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>inv} within CLP (I_{ECLP>inv}) I_{E>inv} Within CLP (I_{ECLP>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Activation time (t_{ECLP>}) I_{E>>} Reset time delay (t_{E>RES}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.002200 /En 0.002200 /En 0.00260.0 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N IE> Element IE> Curve type (I_E>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (t_{ECLP>}) I_E> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (I_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>inv} within CLP (I_{ECLP>inv}) I_{E>inv} Within CLP (I_{ECLP>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>>} Element I_E I_E I_E I_E I_E I_E I_E I_E	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.002200 /En 0.002200 s 0.00200 s 0.00200 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N IE> Element IE> Curve type (I_E>Curve) IEC/BS A, B, C, ANSI/IE IECLP> Activation time (t_{ECLP>}) I_E> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (I_{E>def}) I_{E>def} operating time (t_{E>def}) I_{E>ie>def} Operating time (t_{E>inv}) I_{E>inv} within CLP (I_{ECLP>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E> Element} I_{E>> Reset time delay (t_{E>RES})} 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00100.0 s 0.00210.00 /En 0.00210.00 /En 0.002200 s 0.002200 /En 0.002200 s 0.00200 s 0.00200 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE IECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>inv) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>inv) IE>> Element IECLP>> Activation time (tECLP>>) IE>> Reset time delay (tE>>RES) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.00200 s 0.00100.0 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>inv) IE>> Element IECLP>> Activation time (tECLP>) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def within CLP (IECLP>def) IE>>def within CLP (IECLP>>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.002200 s 0.00200 s 0.00200 s 0.00100.0 s sf) 0.01010.00 /En 0.01010.00 /En
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E>LE> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>inv) IE>> Element IE>Neset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def within CLP (IECLP>>def) IE>>def Operating time (tE>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.00200 s 0.00100.0 s sf) 0.01010.00 /En 0.0310.00 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E>LE> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>Inv) IE>> Element IE>NESEt time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tE>lex) IE>>def operating time (tE>lex) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.0010.00 /En 0.01010.00 /En 0.0310.00 s 0.00200 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E>LE> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>inv) IE>> Element IE>Neset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def within CLP (IECLP>>def) IE>>def Operating time (tE>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.00200 s 0.00100.0 s sf) 0.01010.00 /En 0.0310.00 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>lenv) IE>inv within CLP (IECLP>def) IE>inv within CLP (IECLP>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>lenv) IE>> Element IecLP>> Activation time (tECLP>) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tE>lenv) IE>>def operating time (tE>lenv) IE>>def operating time (tE>lenv) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.0010.00 s sf) 0.01010.00 /En 0.0310.00 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s
 /LR>def Operating time (t_{LR>def}) Residual overcurrent - 50N/51N IE> Element IE> Curve type (I_E>Curve) IEC/BS A, B, C, ANSI/IE /E>LP> Activation time (t_{ECLP>}) IE> Reset time delay (t_E>RES) Definite time 50N/51N First threshold definite time (I_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>def} Operating time (t_{E>def}) I_{E>inv} within CLP (I_{ECLP>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>NE} Reset time delay (t_{E>RES}) Definite time 50N/51N First threshold definite time (I_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>inv} Operating time (t_{E>inv}) I_{E>>} Reset time delay (t_{E>RES}) Definite time 50N/51N Second threshold definite time (I_{E>def}) I_{E>>def} Operating time (t_{E>def}) I_{E>>def} Operating time (t_{E>def}) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.0010.00 s sf) 0.01010.00 /En 0.0310.00 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E>LE> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) /E>def Operating time (tE>lenv) IE>inv within CLP (IECLP>inv) IE>inv within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>lenv) IE>> Element IecLP>> Activation time (tECLP>) Ie>sest time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tE>lenv) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tECLP>>) IE>>def Operating time (tECLP>>) IE>>def Operating time (tECLP>>) IE>>>def operating time (tECLP>>) IE>>>def operating time (tECLP>>) IE>>> Element IE>>> Element IE>>>def Operating time (tECLP>>) IE>>>> Element IE>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.0010.00 /En 0.01010.00 /En 0.0310.00 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.00200 s 0.0010.00 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>Neset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>inv) IE>> Element IECLP>> Activation time (tECLP>>) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def within CLP (IECLP>>def) IE>>>def Operating time (tELP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> Reset time delay (tE>>>RES) Definite time 50N/51N Third threshold definite time (IE>>>def) IECLP>>>def Within CLP (IECLP>>>def) IECLP>>>def Within CLP (IECLP>>>def) IECLP>>>def Operating time (tE>>>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.00100.0 s 0.0010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.0310.00 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>Neset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>inv) IE>> Element IECLP>> Activation time (tECLP>>) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def Operating time (tELP>>) IE>>def within CLP (IECLP>>def) IE>>>def Operating time (tELP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> Reset time delay (tE>>>RES) Definite time 50N/51N Third threshold definite time (IE>>>def) IECLP>>>def Within CLP (IECLP>>>def) IECLP>>>def Within CLP (IECLP>>>def) IECLP>>>def Operating time (tE>>>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.00100.0 s 0.0010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.0310.00 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>def) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>inv Operating time (tE>inv) IE>> Element IECLP>> Activation time (tECLP>) IE>> Reset time delay (tE>>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tE>leclP) IE>>def Operating time (tE>leclP) IE>>def Operating time (tE<le>def)</le> IE>>def Operating time (tE<le>def)</le> IE>>def operating time (tE<le>def)</le> IE>>def operating time (tE<le>def)</le> IE>>>def operating time (tE<le>def)</le> IE>>>def operating time (tE<le>def)</le> IE>>> Element IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> def within CLP (IECLP>>>def) IECLP>>>def Operating time (tE>>>def) IECLP>>>def Operating time (tE>>>def) Maximum number of startings (Restart inl Control window (t_C) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00100.0 s 0.0010.00 /En 0.01010.00 /En 0.0310.00 s 0.00200 s 0.0010.00 s 0.00200 s 0.0010.00 s 0.00200 s 0.0010.00 s 0.00200 s 0.0010.00 s
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 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /ECLP> Activation time (tECLP>) IE> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>> Element IECLP>> Activation time (tECLP>>) IE>> Reset time delay (tE>>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tECLP>>) IE>>def Operating time (tECLP>>) IE>>def operating time (tECLP>>) IE>>>def operating time (tECLP>>) IE>>>def within CLP (IECLP>>def) IE>>>def Operating time (tECLP>>>def) IE>>> Element S0N/51N Second threshold definite time (IE>>def) IE>>> Element IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> def operating time (tE>>>def) IECLP>>> def within CLP (IECLP>>>def) IECLP>>>def Operating time (tE>>>def) Maximum number of startings (Restart inl Control window (t_C) Nst (Starts inside t_C) Tst (Cumulative start time inside t_C)	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00100.0 s 0.0010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.0310.00 s 160 min 130 1600 s
 /LR>def Operating time (tLR>def) Residual overcurrent - 50N/51N IE> Element IE> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Curve type (IE>Curve) IEC/BS A, B, C, ANSI/IE /E> Reset time delay (tE>RES) Definite time 50N/51N First threshold definite time (IE>def) IE>def Operating time (tE>def) Inverse time 50N/51N First threshold inverse time (IE>inv) IE>inv Within CLP (IECLP>inv) IE>inv Operating time (tE>inv) IE>Neset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tECLP>>) IE>>def Operating time (tECLP>>) IE>>def Operating time (tE>lement) IE>>def operating time (tE>lement) IE>> Reset time delay (tE>RES) Definite time 50N/51N Second threshold definite time (IE>def) IE>>def Operating time (tECLP>>def) IE>>> Element IECLP>>> Activation time (tECLP>>>) IE>>> Element IECLP>>> Activation time (tECLP>>>) IE>>> Element IECLP>>> Activation time (tECLP>>>) IECLP>>> Activation time (tECLP>>>) IECLP>>> def operating time (tE>>>def) IECLP>>> def operating time (tE>>>def) IECLP>>> def operating time (tE>>>def) IECLP>>>def Operating time (tE>>>def) IECLP>>>def Operating time (tE>>>def) IECLP>>>def Operating time (tE>>>def) 	0.10200 s DEFINITE EE MI, VI, EI, EM 0.00200 s 0.00210.00 /En 0.00210.00 /En 0.002200 /En 0.002200 /En 0.002200 /En 0.002200 s 0.00200 s 0.0010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.01010.00 /En 0.0310.00 s 160 min 130

_	Breaker failure - BF	
	BF Phase current threshold (<i>I</i> _{BF} >)	0.051.00 <i>I</i> _n
	BF Residual current threshold (<i>I</i> _{EBF} >)	0.012.00 / _{En}
	BF Time delay (<i>t</i> _{BF})	0.0610.00 s
_	Selective block - BLOCK2	
	Selective block IN:	
	• BLIN Max activation time for phase p	
	• BLIN Max activation time for ground	0.1010.00 s protections (روم ال
	BEIN Max detivation time for ground	0.1010.00 s
	Selective block OUT:	
	 BLOUT Dropout time delay for phase eler BLOUT Drop-out time delay for ground eler 	nents (t_{F-IPh})0.001.00 s
	 BLOUT Drop-out time delay for phase and 	around elements ($t_{E_1B_2/1E}$)
	,,	0.001.00 s
—	CT supervision - 74CT	
	74CT Threshold (<i>S<</i>)	0.100.95
	74CT Overcurrent threshold (<i>I</i> *) <i>S</i> < Operating time (<i>t</i> _S <)	0.101.00 / _n 0.03200 s
		0.00200 0
_	Circuit Breaker supervision	
	Number of CB trips (<i>N.Open</i>)	010000
	Cumulative CB tripping currents (<i>Suml</i>) CB opening time for I^2t calculation (<i>t</i>	
	Cumulative CB tripping I^2t (SumI^2t)	05000 (<i>I</i> _n)²⋅s
	CB max allowed opening time (<i>t</i> _{break} >)	0.051.00 s
	Pilot wire diagnostic	
_	BLOUT1 Diagnostic pulses period (<i>Puls</i>	seBLOUT1)
		OFF - 0.1-1-5-10-60-120 s
	METERING & RECORDING	
_	Measured parameters Direct:	
	• Frequency	f
	• Fundamental RMS phase currents	I _{L1} , I _{L2} , I _{L3}
	• Fundamental RMS residual current	Ι _Ε
	Calculated: • Thermal image	DTheta
	 Maximum current between IL1-IL2-II 	
	• Minimum current between /L1-/L2-/L	
	• Average current between /L1-/L2-/L3	, I _L
	Sequence: Positive sequence current 	/1
	Negative sequence current	I_2
	Negative sequence current/positive se	quence current ratio I_2/I_1
	2nd harmonic:	
	• Second harmonic phase currents <i>3rd harmonic:</i>	/ _{L1-2nd} , / _{L2-2nd} , / _{L3-2nd}
	Third harmonic phase currents	/L1-3rd, /L2-3rd, /L3-3rd
	• Third harmonic residual current	/ _{E-3rd}
	4th harmonic:	
	 Fourth harmonic phase currents 	/ _{L1-4th} , / _{L2-4th} , / _{L3-4th}
	5th harmonic:	
	• Fifth harmonic phase currents	/ _{L1-5th} , / _{L2-5th} , / _{L3-5th}
	 Demand phase currents: Phase fixed currents demand 	I _{L1FIX} , I _{L2FIX} , I _{L3FIX}
	Phase rolling currents demand	ILIROL, IL2ROL, IL3ROL
	Phase peak currents demand	Ilimax, Ilimax, Ilimax
	Phase minimum currents demand	I _{l1min} , I _{l2min} , I _{l3min}
_	Event recording (SER)	
	Number of events	300
	Recording mode	circular
	Trigger: • Output relays switching	K1K6K10
	 Binary inputs switching Setting changes 	IN1, IN2INx

Binary inputs switchingSetting changes

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Data recorded:

• Event counter (resettable by ThySetter) 0...10⁹

- Event cause
- binary input/output relay/setting changes Date and time • Time stamp

— Fault recording (SFR)	
Number of faults	20
Recording mode	circular
<i>Trigger:</i> External trigger (binary inputs) 	IN1, IN2INx
• Element pickup (OFF-ON transition)	Start/Trip
Data recorded:	
• Time stamp	Date and time
 Fault cause Fault counter (resettable by ThySett) 	start, trip, binary input er) 010 ⁹
 Fundamental RMS phase currents 	<i>I</i> _{L1r} , <i>I</i> _{L2r} , <i>I</i> _{L3r}
 Fundamental RMS residual current 	
Thermal image	DTheta-r
 Binary inputs state Output relays state 	IN1, IN2INx K1K6K10
 Fault cause info (operating phase) 	L1, L2, L3
, , , , , , , , , , , , , , , , , , ,	
— Digital Fault Recorder (Oscillogra	phy)
File format	COMTRADE
Records Recording mode	depending on setting ^[1] circular
Sampling rate	24 samples per cycle
Trigger setup:	,
Pre-trigger time	0.051.00 s
Post-trigger time	0.0560.00 s
Trigger from inputsTrigger from outputs	IN1, IN2INx K1K6K10
Communication	ThySetter
Set sample channels:	Inyoottor
 Instantaneous currents 	<i>i</i> L1, <i>i</i> L2, <i>i</i> L3, <i>i</i> E
Set analog channels (Analog 112):	
 Frequency 	f
 Fundamental RMS phase currents 	I _{L1} , I _{L2} , I _{L3} , I ₁ , I ₂
 Fundamental RMS residual current 	
 Fundamental RMS positive and neg Negative sequence / positive seque 	
Temperature	T1T8
Set digital channels (Digital 112):	
Output relays state	K1K6K10
 Binary inputs state 	IN1, IN2INx
Note [1] - For instance, with following setting:	_
Pre-trigger time and Post-trigger tim Sampled abapted	
Sampled channelsAnalog channels	il1, il2, il3, ie Il1, Il2, Il3, IE, I1, I2
	K2 K3 K4 K5 K6 IN1 IN2

• Digital channels K1, K2, K3, K4, K5, K6, IN1, IN2

up to 450 records can be stored with f = 50 Hz

Connection diagram example



DIMENSIONS

FRONT VIEW

REAR VIEW



SIDE VIEW



RACK MOUNTING





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